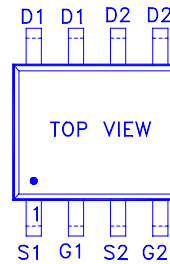
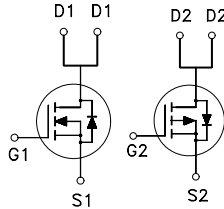


**PRODUCT SUMMARY**

|           |               |              |       |
|-----------|---------------|--------------|-------|
|           | $V_{(BR)DSS}$ | $R_{DS(ON)}$ | $I_D$ |
| N-Channel | 30            | 27.5m        | 7A    |
| P-Channel | -30           | 45m          | -5A   |



G : GATE  
D : DRAIN  
S : SOURCE

**ABSOLUTE MAXIMUM RATINGS ( $T_C = 25\text{ }^\circ\text{C}$  Unless Otherwise Noted)**

| PARAMETERS/TEST CONDITIONS           |                                  | SYMBOL         | N-Channel  | P-Channel | UNITS            |
|--------------------------------------|----------------------------------|----------------|------------|-----------|------------------|
| Drain-Source Voltage                 |                                  | $V_{DS}$       | 30         | -30       | V                |
| Gate-Source Voltage                  |                                  | $V_{GS}$       | $\pm 20$   | $\pm 20$  | V                |
| Continuous Drain Current             | $T_C = 25\text{ }^\circ\text{C}$ | $I_D$          | 7          | -5        | A                |
|                                      | $T_C = 70\text{ }^\circ\text{C}$ |                | 6          | -4        |                  |
| Pulsed Drain Current <sup>1</sup>    |                                  | $I_{DM}$       | 20         | -20       |                  |
| Power Dissipation                    | $T_C = 25\text{ }^\circ\text{C}$ | $P_D$          | 2          |           | W                |
|                                      | $T_C = 70\text{ }^\circ\text{C}$ |                | 1.3        |           |                  |
| Junction & Storage Temperature Range |                                  | $T_j, T_{stg}$ | -55 to 150 |           | $^\circ\text{C}$ |

**THERMAL RESISTANCE RATINGS**

| THERMAL RESISTANCE  | SYMBOL          | TYPICAL | MAXIMUM | UNITS                       |
|---------------------|-----------------|---------|---------|-----------------------------|
| Junction-to-Ambient | $R_{\theta JA}$ |         | 62.5    | $^\circ\text{C} / \text{W}$ |

<sup>1</sup>Pulse width limited by maximum junction temperature.

<sup>2</sup>Duty cycle  $\leq 1\%$

**ELECTRICAL CHARACTERISTICS ( $T_C = 25\text{ }^\circ\text{C}$ , Unless Otherwise Noted)**

| PARAMETER                      | SYMBOL        | TEST CONDITIONS                               | LIMITS |     |      | UNIT      |      |
|--------------------------------|---------------|---|--------|-----|------|-----------|------|
|                                |               |   | MIN    | TYP | MAX  |           |      |
| <b>STATIC</b>                  |               |   |        |     |      |           |      |
| Drain-Source Breakdown Voltage | $V_{(BR)DSS}$ | $V_{GS} = 0\text{V}, I_D = 250\mu\text{A}$    | N-Ch   | 30  |      | V         |      |
|                                |               | $V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$   | P-Ch   | -30 |      |           |      |
| Gate Threshold Voltage         | $V_{GS(th)}$  | $V_{DS} = V_{GS}, I_D = 250\mu\text{A}$       | N-Ch   | 1   | 1.5  |           | 2.5  |
|                                |               | $V_{DS} = V_{GS}, I_D = -250\mu\text{A}$      | P-Ch   | -1  | -1.5 |           | -2.5 |
| Gate-Body Leakage              | $I_{GSS}$     | $V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$ | N-Ch   |     |      | $\pm 100$ |      |
|                                |               | $V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$ | P-Ch   |     |      | $\pm 100$ |      |

|                                       |                          |  |      |     |      |         |   |
|---------------------------------------|--------------------------|--|------|-----|------|---------|---|
| Zero Gate Voltage Drain Current       | $I_{DSS}$                | $V_{DS} = 24V, V_{GS} = 0V$                    | N-Ch |     | 1    | $\mu A$ |   |
|                                       |                          | $V_{DS} = -24V, V_{GS} = 0V$                   | P-Ch |     | -1   |         |   |
|                                       |                          | $V_{DS} = 20V, V_{GS} = 0V, T_J = 55^\circ C$  | N-Ch |     | 10   |         |   |
|                                       |                          | $V_{DS} = -20V, V_{GS} = 0V, T_J = 55^\circ C$ | P-Ch |     | -10  |         |   |
| On-State Drain Current <sup>1</sup>   | $I_{D(ON)}$              | $V_{DS} = 5V, V_{GS} = 10V$                    | N-Ch | 20  |      | A       |   |
|                                       |                          | $V_{DS} = -5V, V_{GS} = -10V$                  | P-Ch | -20 |      |         |   |
| Drain-Source Resistance <sup>1</sup>  | On-State<br>$R_{DS(ON)}$ | $V_{GS} = 4.5V, I_D = 6A$                      | N-Ch |     | 30   | 40      | m |
|                                       |                          | $V_{GS} = -4.5V, I_D = -4A$                    | P-Ch |     | 62   | 80      |   |
|                                       |                          | $V_{GS} = 10V, I_D = 7A$                       | N-Ch |     | 20.5 | 27.5    |   |
|                                       |                          | $V_{GS} = -10V, I_D = -5A$                     | P-Ch |     | 37.5 | 45      |   |
| Forward Transconductance <sup>1</sup> | $g_{fs}$                 | $V_{DS} = 5V, I_D = 7A$                        | N-Ch |     | 16   |         | S |
|                                       |                          | $V_{DS} = -5V, I_D = -5A$                      | P-Ch |     | 13   |         |   |

| DYNAMIC                          |              |  |      |  |      |      |      |
|----------------------------------|--------------|--|------|--|------|------|------|
| Input Capacitance                | $C_{iss}$    | N-Channel  | N-Ch |  | 680  |      | $pF$ |
|                                  |              | P-Channel  | P-Ch |  | 780  |      |      |
| Output Capacitance               | $C_{oss}$    | $V_{GS} = 0V, V_{DS} = 15V, f = 1MHz$<br>N-Channel                         | N-Ch |  | 105  |      | $pF$ |
|                                  |              | P-Channel  | P-Ch |  | 145  |      |      |
| Reverse Transfer Capacitance     | $C_{rss}$    | $V_{GS} = 0V, V_{DS} = -15V, f = 1MHz$<br>N-Channel                        | N-Ch |  | 75   |      | $pF$ |
|                                  |              | P-Channel  | P-Ch |  | 79   |      |      |
| Total Gate Charge <sup>2</sup>   | $Q_g$        | N-Channel<br>$V_{DS} = 0.5 \cdot V_{(BR)DSS}, V_{GS} = 10V,$<br>$I_D = 7A$ | N-Ch |  | 14   |      | nC   |
|                                  |              | P-Channel  | P-Ch |  | 15.1 |      |      |
| Gate-Source Charge <sup>2</sup>  | $Q_{gs}$     | N-Channel  | N-Ch |  | 1.9  |      |      |
|                                  |              | P-Channel  | P-Ch |  | 2.1  |      |      |
| Gate-Drain Charge <sup>2</sup>   | $Q_{gd}$     | $V_{DS} = 0.5 \cdot V_{(BR)DSS}, V_{GS} = -10V,$<br>$I_D = -5A$            | N-Ch |  | 3.3  |      | nC   |
|                                  |              | P-Channel  | P-Ch |  | 4.0  |      |      |
| Turn-On Delay Time <sup>2</sup>  | $t_{d(on)}$  | N-Channel  | N-Ch |  | 4.6  | 7    | nS   |
|                                  |              | P-Channel  | P-Ch |  | 7.7  | 11.5 |      |
| Rise Time <sup>2</sup>           | $t_r$        | $V_{DD} = 10V$<br>$I_D \cong 1A, V_{GS} = 10V, R_{GEN} = 3$                | N-Ch |  | 4    | 6    | nS   |
|                                  |              | P-Channel  | P-Ch |  | 5.7  | 8.5  |      |
| Turn-Off Delay Time <sup>2</sup> | $t_{d(off)}$ | P-Channel  | N-Ch |  | 20   | 30   | nS   |
|                                  |              |  | P-Ch |  | 20   | 30   |      |
| Fall Time <sup>2</sup>           | $t_f$        | $V_{DD} = -10V$<br>$I_D \cong -1A, V_{GS} = -10V, R_{GEN} = 3$             | N-Ch |  | 5    | 8    | nS   |
|                                  |              |  | P-Ch |  | 9.5  | 14   |      |

**SOURCE-DRAIN DIODE RATINGS AND CHARACTERISTICS (T<sub>C</sub> = 25 °C)**

|                              |                 |  |      |  |      |   |
|------------------------------|-----------------|--|------|--|------|---|
| Continuous Current           | I <sub>S</sub>  |  | N-Ch |  | 1.3  | A |
|                              |                 |  | P-Ch |  | -1.3 |   |
| Pulsed Current <sup>3</sup>  | I <sub>SM</sub> |  | N-Ch |  | 2.6  |   |
|                              |                 |  | P-Ch |  | -2.6 |   |
| Forward Voltage <sup>1</sup> | V <sub>SD</sub> | I <sub>F</sub> = 1A, V <sub>GS</sub> = 0V  | N-Ch |  | 1    | V |
|                              |                 | I <sub>F</sub> = -1A, V <sub>GS</sub> = 0V | P-Ch |  | -1   |   |

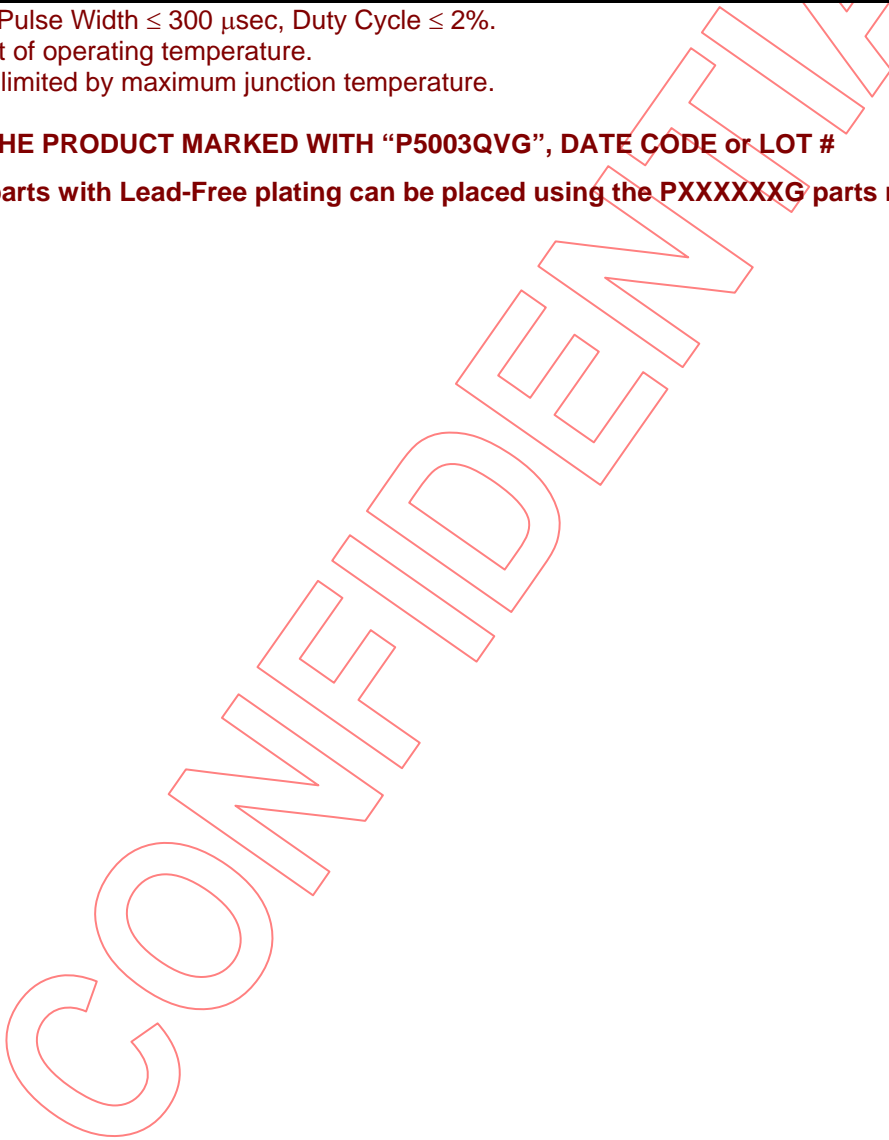
<sup>1</sup>Pulse test : Pulse Width ≤ 300 μsec, Duty Cycle ≤ 2%.

<sup>2</sup>Independent of operating temperature.

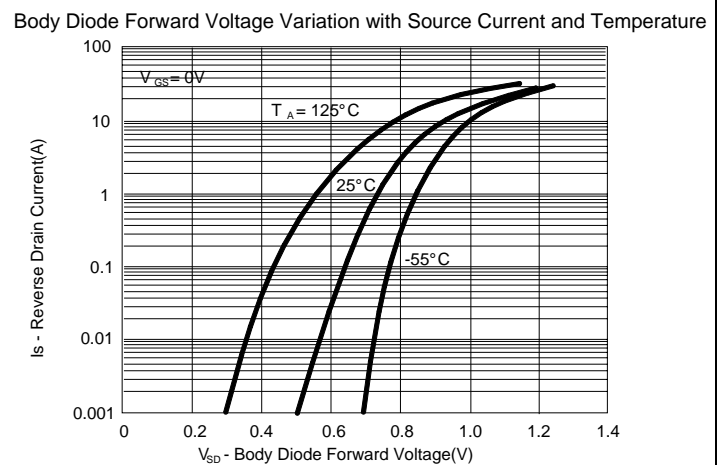
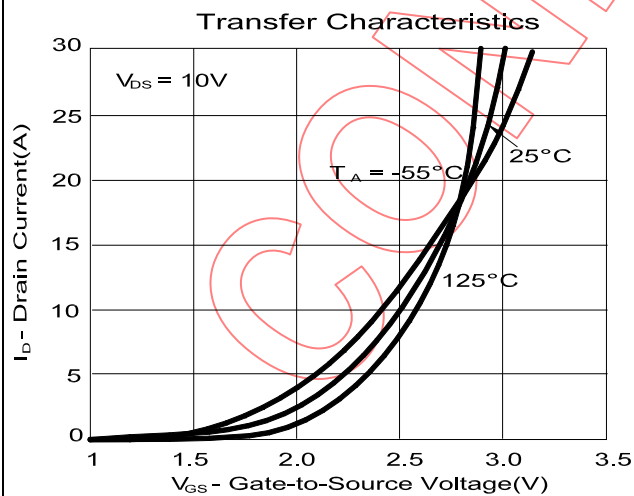
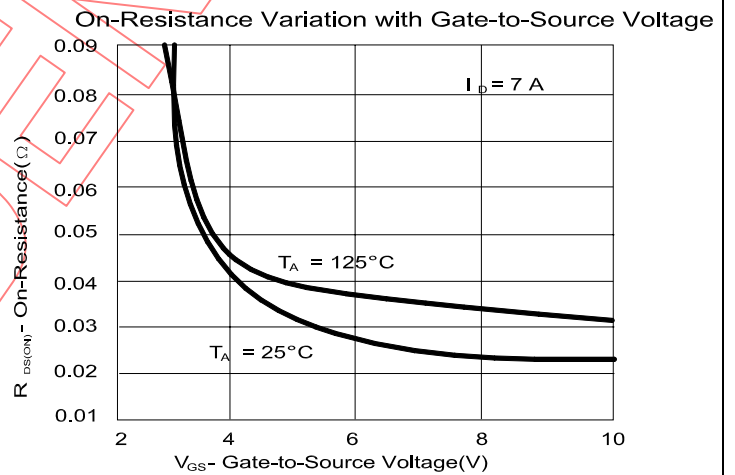
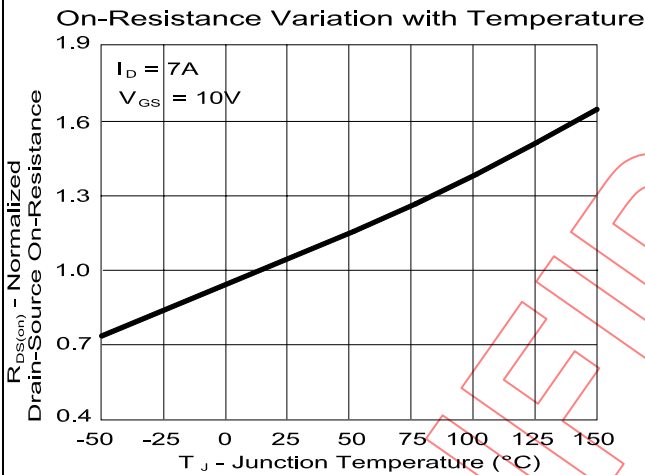
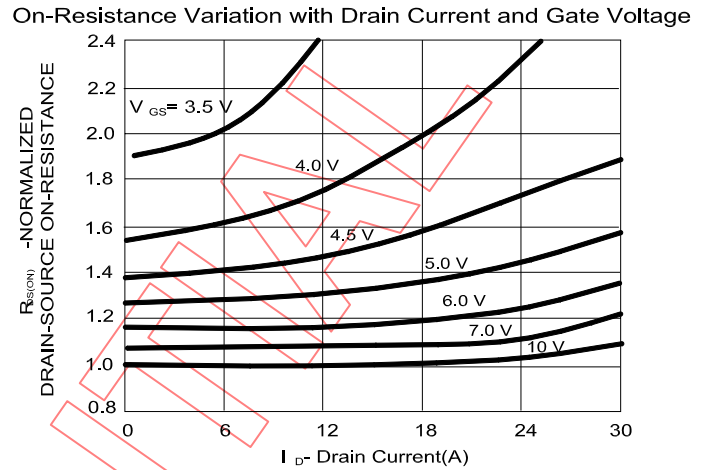
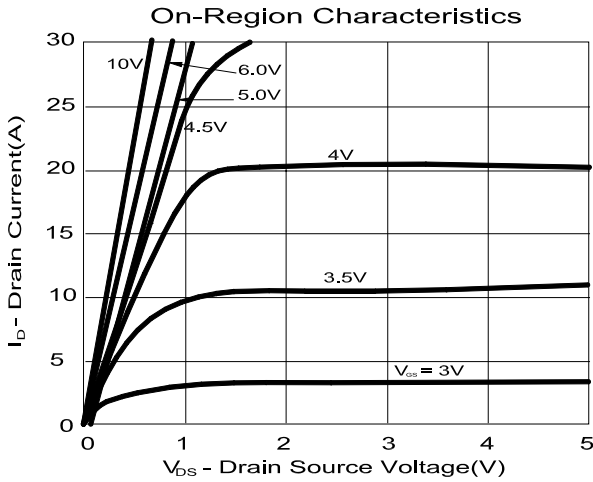
<sup>3</sup>Pulse width limited by maximum junction temperature.

**REMARK: THE PRODUCT MARKED WITH “P5003QVG”, DATE CODE or LOT #**

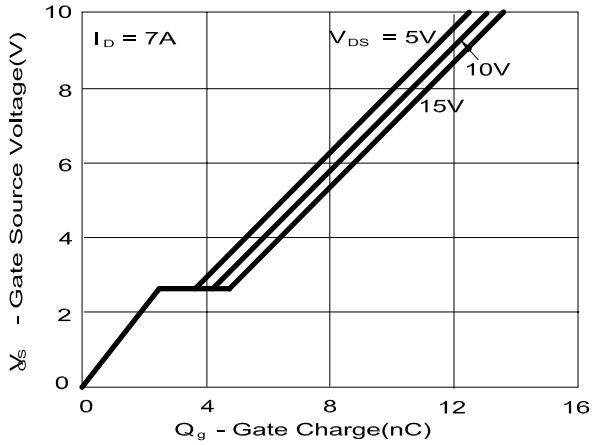
**Orders for parts with Lead-Free plating can be placed using the PXXXXXXG parts name.**



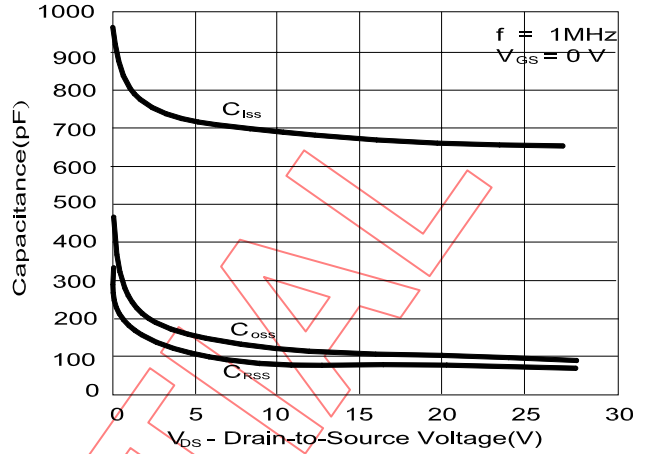
**N-CHANNEL**



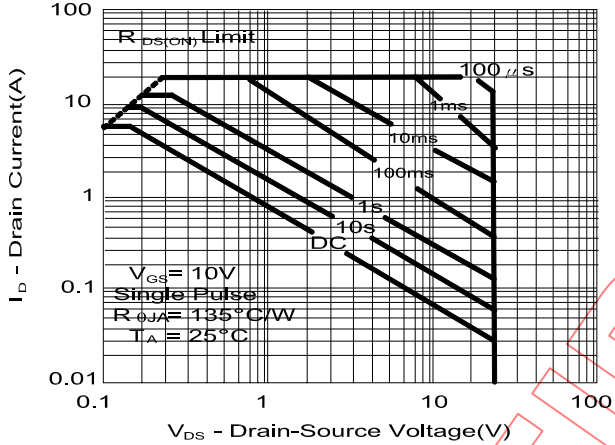
**Gate Charge Characteristics**



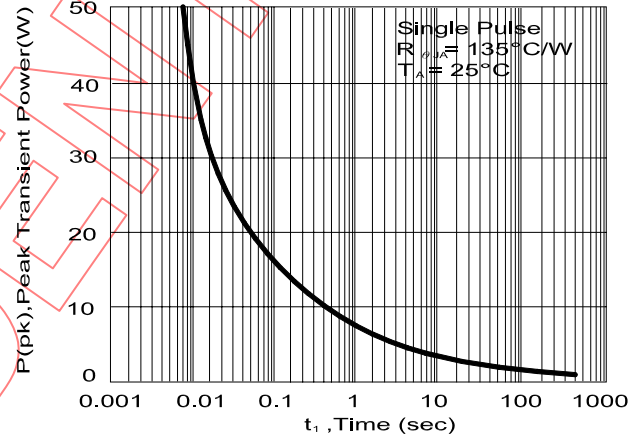
**Capacitance Characteristics**



**Maximum Safe Operating Area**



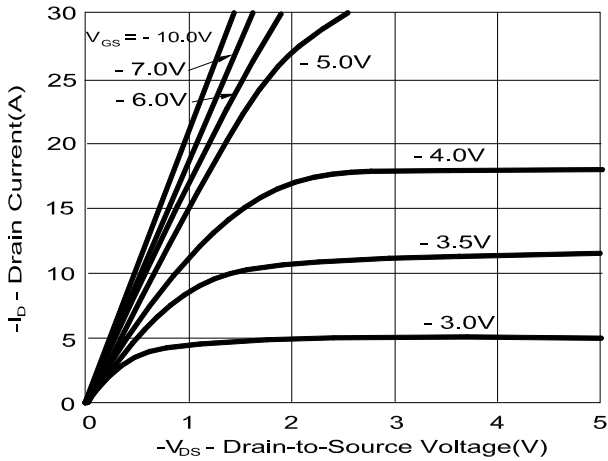
**Single Pulse Maximum Power Dissipation**



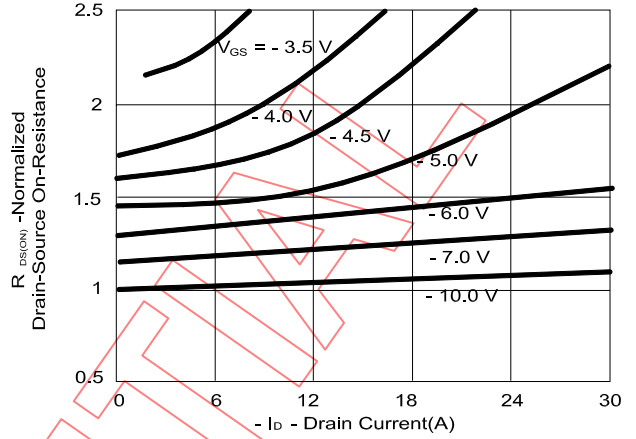
CONFIDENTIAL

**P-CHANNEL**

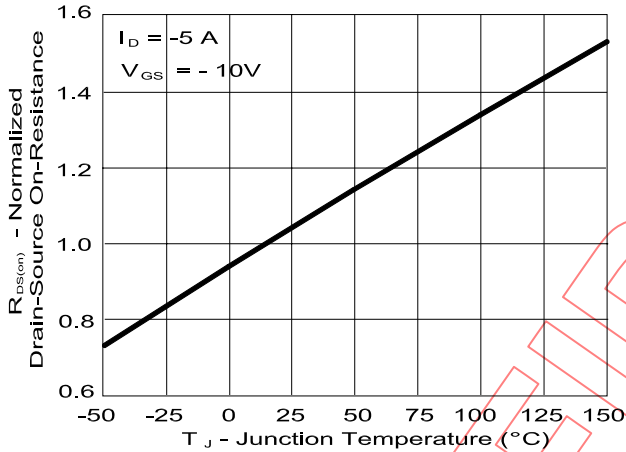
On-Region Characteristics



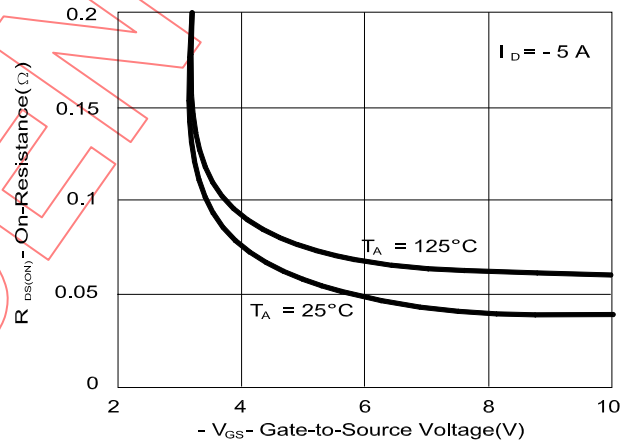
On-Resistance Variation with Drain Current and Gate Voltage



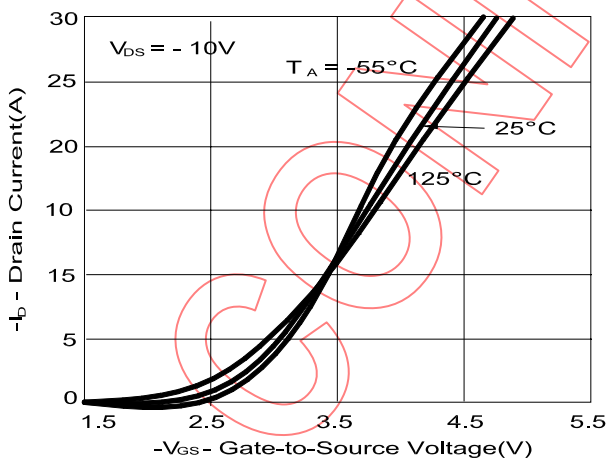
On-Resistance Variation with Temperature



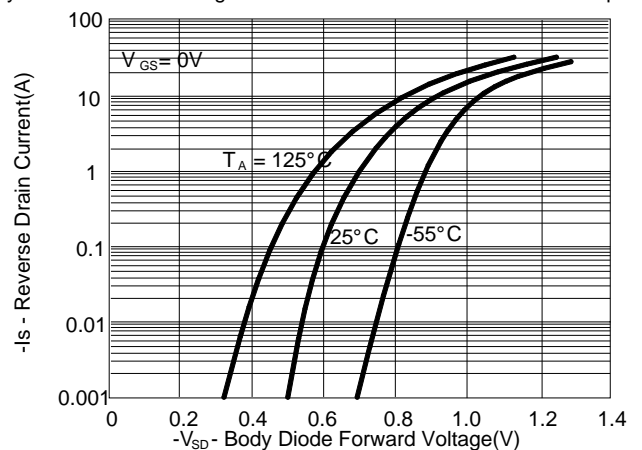
On-Resistance Variation with Gate-to-Source Voltage

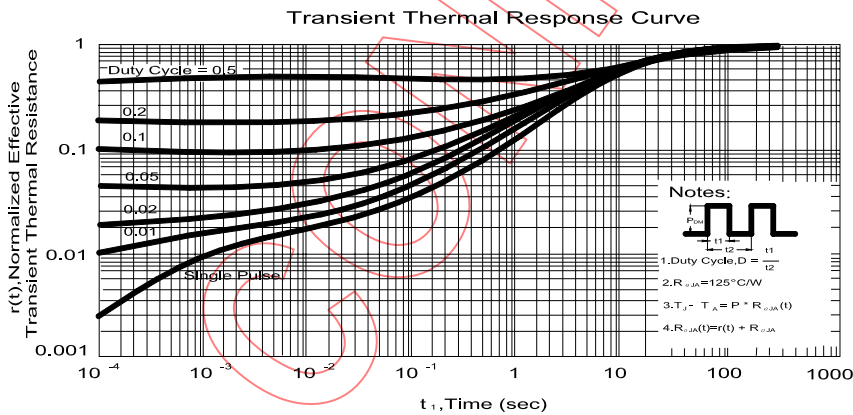
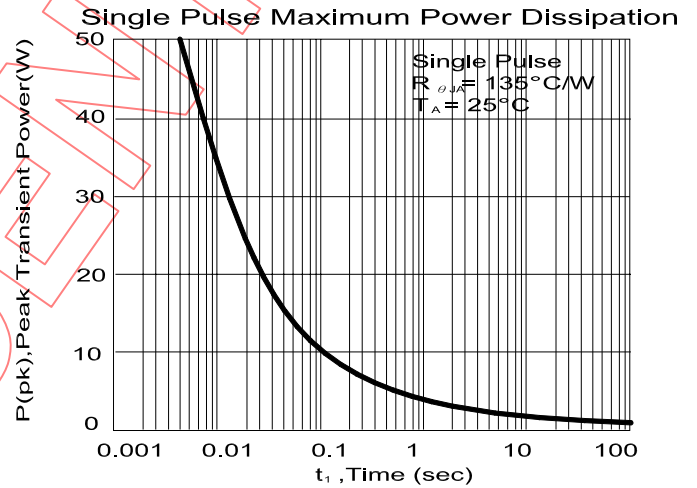
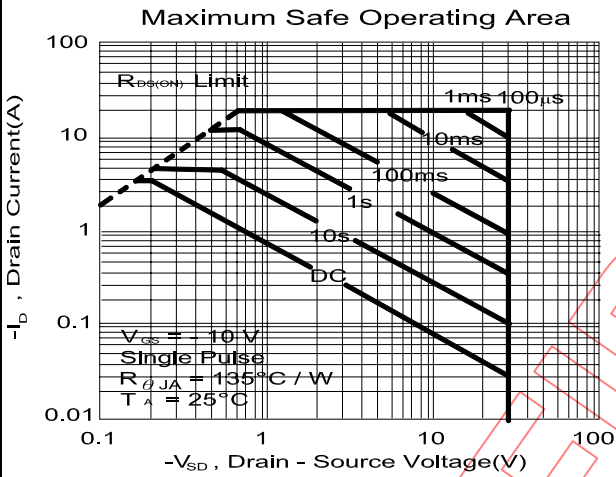
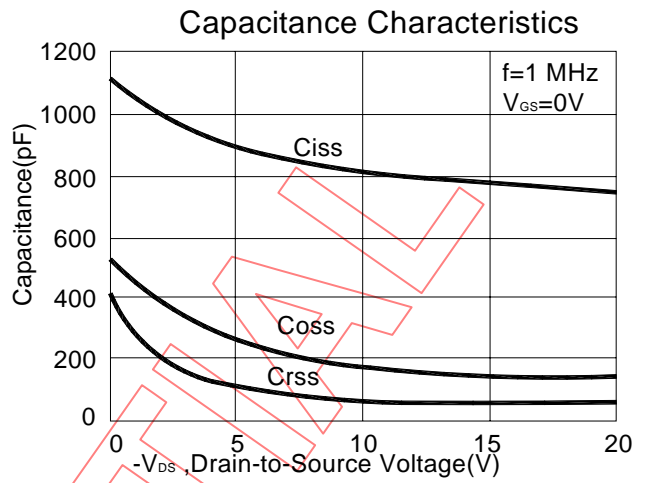
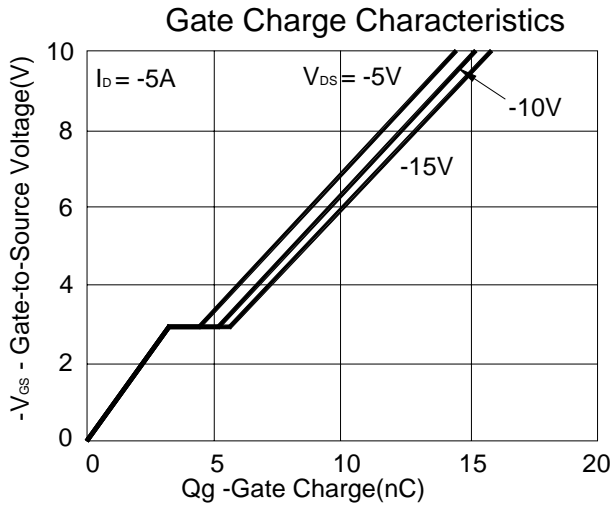


Transfer Characteristics



Body Diode Forward Voltage Variation with Source Current and Temperature





**SOIC-8(D) MECHANICAL DATA**

| Dimension | mm   |       |      | Dimension | mm   |       |      |
|-----------|------|-------|------|-----------|------|-------|------|
|           | Min. | Typ.  | Max. |           | Min. | Typ.  | Max. |
| A         | 4.8  | 4.9   | 5.0  | H         | 0.5  | 0.715 | 0.83 |
| B         | 3.8  | 3.9   | 4.0  | I         | 0.18 | 0.254 | 0.25 |
| C         | 5.8  | 6.0   | 6.2  | J         |      | 0.22  |      |
| D         | 0.38 | 0.445 | 0.51 | K         | 0°   | 4°    | 8°   |
| E         |      | 1.27  |      | L         |      |       |      |
| F         | 1.35 | 1.55  | 1.75 | M         |      |       |      |
| G         | 0.1  | 0.175 | 0.25 | N         |      |       |      |

